Vincotech

10-EZ126TA025M7-L858F73T

target datasheet

***flow*PACK E1** **1200 V / 25 A**

Topology features

- Inverter
- Kelvin Emitter for improved switching performance
- Tandem inverter diode
- Temperature sensor

Component features

- Easy paralleling
- Low turn-off losses
- Low collector emitter saturation voltage
- Positive temperature coefficient
- Short tail current
- Switching optimized for EMC

Housing features

- Base isolation: Al_2O_3
- Convex shaped substrate for superior thermal contact
- Compact housing
- CTI600 housing material
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

Target applications

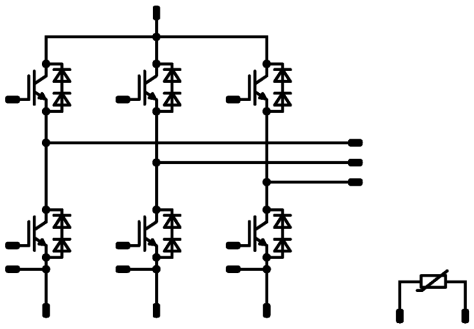
- Elevator Drives
- Industrial Drives
- Servo Drives

Types

- 10-EZ126TA025M7-L858F73T

flow E1 12 mm housing

Schematic



Maximum Ratings

T_j = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ T_s = 80 °C	37	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	50	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ T_s = 80 °C	93	W
Gate-emitter voltage	V_{GES}		±20	V
Short circuit ratings	t_{SC}	V_{GE} = 15 V, V_{CC} = 800 V T_j = 150 °C	9,5	µs
Maximum junction temperature	T_{jmax}		175	°C
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		1300	V
Forward current (DC current)[2]	I_F	$T_j = T_{jmax}$ T_s = 80 °C	23	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	60	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ T_s = 80 °C	67	W
Maximum junction temperature	T_{jmax}		175	°C

[1]Calculation based on chip supplier datasheet at T_j=175°C

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40…+125	°C
Operation temperature under switching condition	T_{jop}		-40…+(T_{jmax} - 25)	°C

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage t_p = 2 s	6000	V
Creepage distance			>12,7	mm
Clearance			8,62	mm
Comparative Tracking Index	CTI		≥ 600	

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	
Inverter Switch										
Static										
Gate-emitter threshold voltage	$V_{GE(th)}$			10	0,0025	25	5,4	6	6,6	V
Collector-emitter saturation voltage	V_{CEsat}		15		25	25 150		1,65 1,95	2,1	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			70	µA
Gate-emitter leakage current	I_{GES}		20	0		25			200	nA
Internal gate resistance	r_g							None		Ω
Input capacitance	C_{ies}							4800		pF
Output capacitance	C_{oes}		0	10		25		170		pF
Reverse transfer capacitance	C_{res}							57		pF
Gate charge	Q_g	V_{CC} = 600 V	0/15		25	25		180		nC
Thermal										
Thermal resistance junction to sink	$R_{th(j-s)}$	λ_{paste} = 3,4 W/mK (PSX)						1,02		K/W
Inverter Diode										
Static										
Forward voltage	V_F				20	25		2,9	3,84	V
Reverse leakage current	I_R	V_r = 1300 V				25			1,28	µA
Thermal										
Thermal resistance junction to sink	$R_{th(j-s)}$	λ_{paste} = 3,4 W/mK (PSX)						1,42		K/W

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	
Thermistor										
Static										
Rated resistance	R					25		5		kΩ
Deviation of R100	$\Delta_{R/R}$	R_{100} = 499 Ω				100	3,2		3,3	%
Power dissipation	P					25		130		mW
Power dissipation constant	d					25		1,3		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3380		K
Vincotech Thermistor Reference									V	

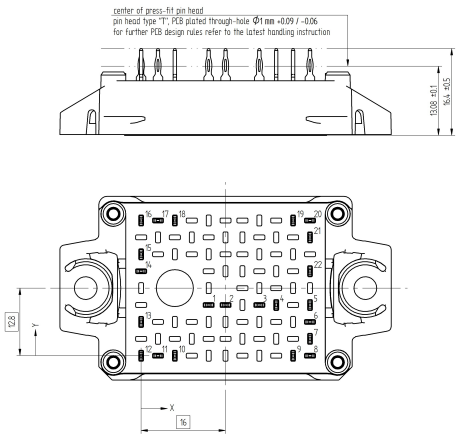
Ordering Code	
Version	**Ordering Code**
Without thermal paste	10-EZ126TA025M7-L858F73T
With thermal paste (5,2 W/mK, PTM6000HV)	10-EZ126TA025M7-L858F73T-/7/

Marking

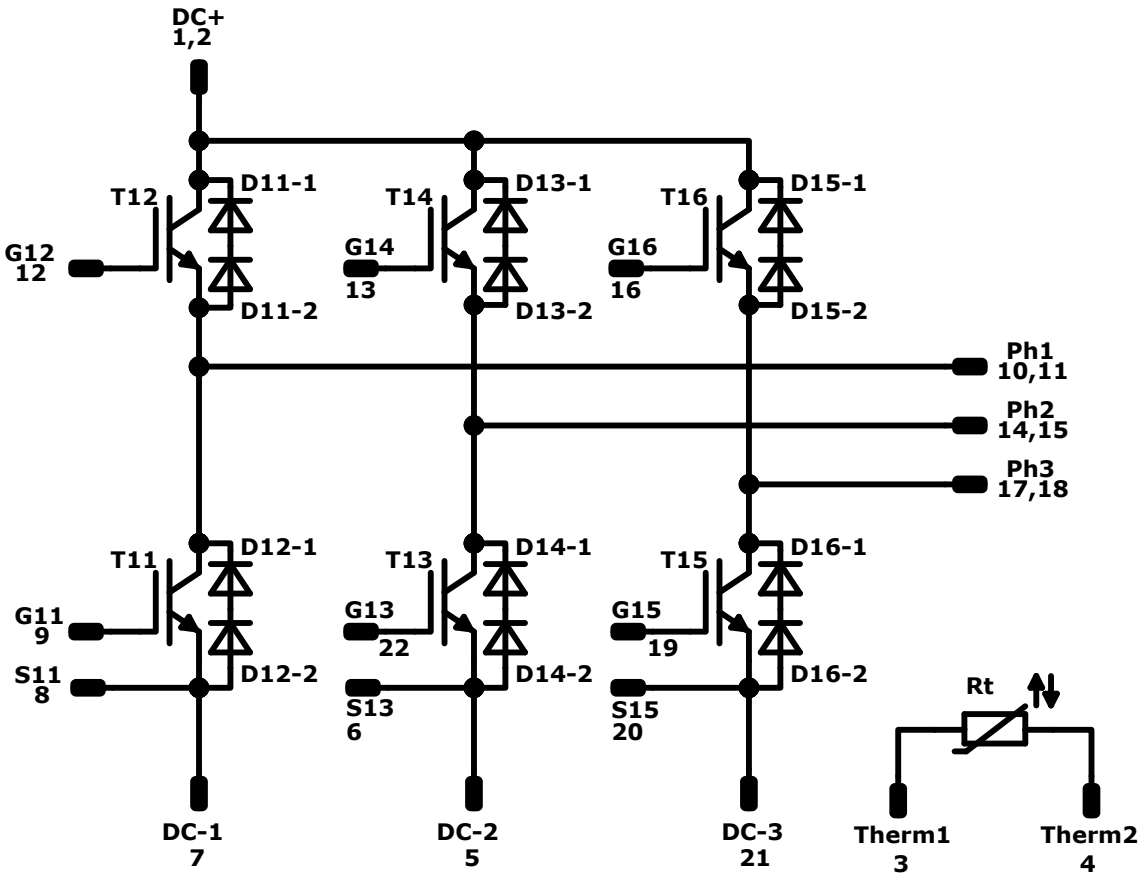
	Name		Date code	UL & VIN	Lot	Serial
Text	NN-NNNNNNNNNNNNNN-TTTTTTVV		WWYY	UL VIN	LLLLL	SSSS
Datamatrix	**Type&Ver**	**Lot number**	**Serial**	**Date code**		
	TTTTTTVV	LLLLL	SSSS	WWYY		

Outline

Pin table [mm]			
Pin	X	Y	Function
1	12,8	9,6	DC+
2	16	9,6	DC+
3	22,4	9,6	Therm1
4	25,6	9,6	Therm2
5	32	9,6	DC-2
6	32	6,4	S13
7	32	3,2	DC-1
8	32	0	S11
9	28,8	0	G11
10	6,4	0	Ph1
11	3,2	0	Ph1
12	0	0	G12
13	0	6,4	G14
14	0	16	Ph2
15	0	19,2	Ph2
16	0	25,6	G16
17	3,2	25,6	Ph3
18	6,4	25,6	Ph3
19	28,8	25,6	G15
20	32	25,6	S15
21	32	22,4	DC-3
22	32	16	G13



Pinout



Identification					
ID	**Component**	**Voltage**	**Current**	**Function**	**Comment**
T11, T12, T13, T14, T15, T16	IGBT	1200 V	25 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1300 V	20 A	Inverter Diode	
Rt	NTC			Thermistor	

Packaging instruction				
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for *flow* E1 packages see vincotech.com website.

Package data
Package data for *flow* E1 packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition $T_{j,op}$=175°C and up to 3500VAC/1min isolation voltage. For more information see vincotech.com website.

Document No.:	Date:	Modification:	Pages
10-EZ126TA025M7-L858F73T-T1-14	22 Aug. 2025	Initial Release	

Product status definition		
Datasheet Status	**Product Status**	**Definition**
Target	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. The data contained is exclusively intended for technically trained staff.